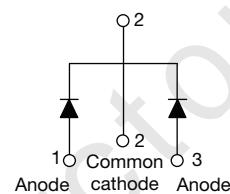



●Features:

- Common Cathode Structure
- Low Power Loss and High Efficiency
- Low Forward Voltage Drop
- High Surge Capability

●Application:

- High Frequency Switch
- Free Wheeling, and Polarity Protection Applications


Absolute Maximum Ratings(Tc=25°C unless otherwise noted)

Symbol	Parameter	Value	Unit
V _{RRM}	Maximum Repetitive Reverse Voltage	150	V
V _R	Maximum DC Reverse Voltage	150	V
I _{F(AV)}	Average Rectified Forward Current, Tc=120°C	10(Per Leg) 20(Per Device)	A
I _{FSM}	Peak Forward Surge Current, 8.3ms Half Sine wave	150	A
T _j	Operating Junction Temperature	150	°C
T _{stg}	Storage Temperature Range	-55 to +150	°C

Thermal Characteristics(Tc=25°C unless otherwise noted)

Symbol	Parameter	Max	Unit
R _{θJC}	Thermal Resistance, Junction to Case Per Leg	2.2	°C /W
R _{θJA}	Thermal Resistance, Junction to Ambient Per Leg	92	°C /W

Electrical Characteristics(Tc=25°C unless otherwise noted)

Symbol	Parameter	Test Conditions	Min	Max	Unit
V _{RRM}	Maximum Repetitive Reverse Voltage	I _R =100μA	150		V
I _R	Reverse Current	V _R =150V Tc=25°C V _R =150V Tc=125°C		0.1 5	mA
V _F	Forward Voltage	I _F =10A Tc=25°C I _F =10A Tc=125°C I _F =20A Tc=25°C I _F =20A Tc=125°C		0.97 0.87 1.07 0.97	V

Typical Performance Characteristics

Figure 1. Forward Current Characteristics

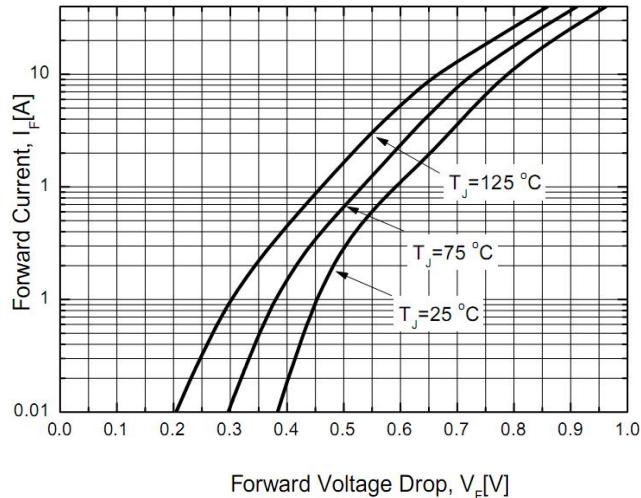


Figure 2. Reverse Leakage Current

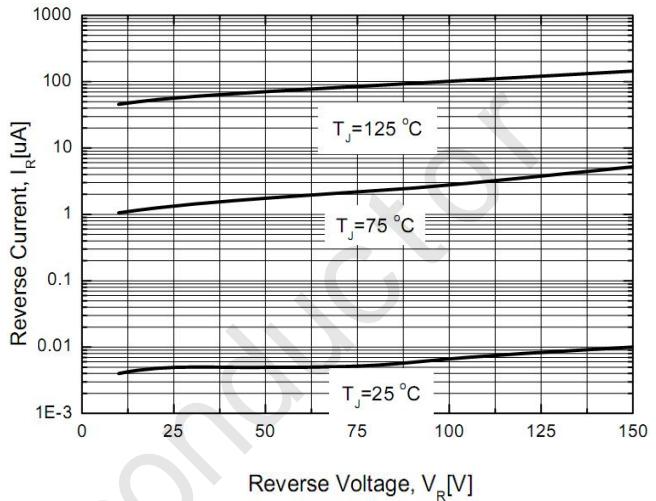


Figure 3. Junction Capacitance

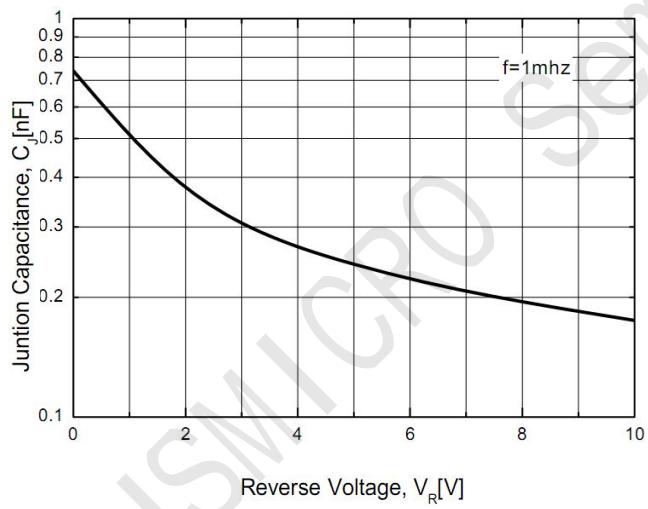
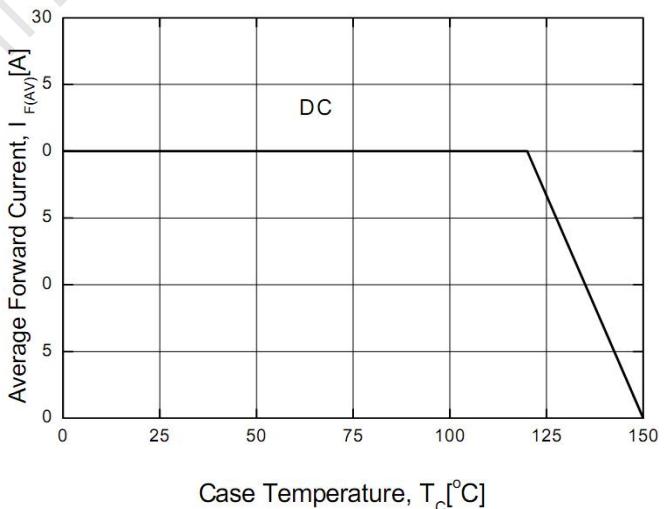
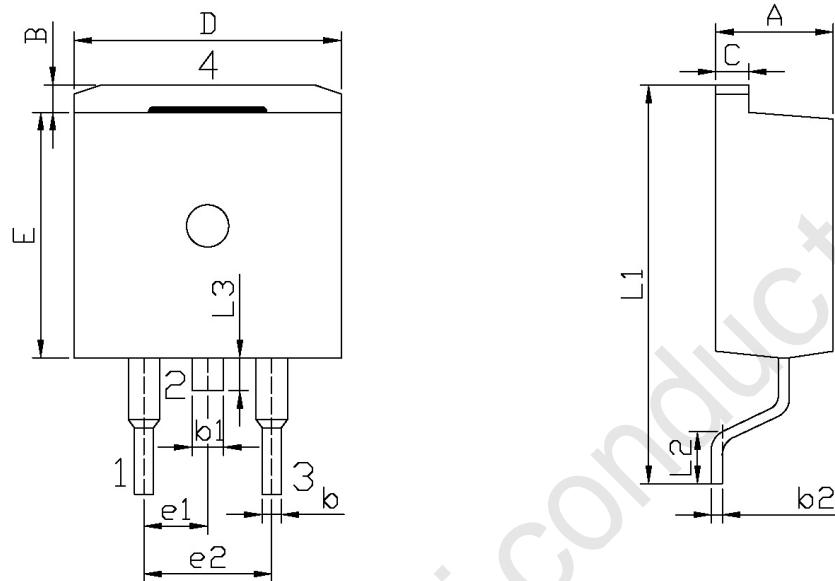


Figure 4. Power Derating





单位: mm

Symbol	Dimensions In Millimeters		Symbol	Dimensions In Millimeters	
	Min	Max		Min	Max
A	4.30	4.70	E	9.00	9.40
B	1.00	1.40	e1	2.34	2.74
b	0.70	0.90	e2	4.88	5.28
b1	1.15	1.35	L1	15.00	16.00
b2	0.40	0.60	L2	2.24	2.84
C	1.20	1.40	L3	1.20	1.60
D	9.80	10.20			

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